NSN 5962-01-188-8747



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-188-8747 **Body Length:** Between 1.060 inches and 1.110 inches **Body Width:** Between 0.380 inches and 0.400 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 440.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and high performance and low power and w/enable and bidirectional **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 19 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 400.00 nanoseconds propagation delay time, low to high level output and 400.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 22 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli